Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Plastic	
Overall Length:	
0.1197 inches	
Overall Height:	
0.0472 inches	
Overall Width:	
0.1023 inches	
Joint Electronic Device Engineering Council/jedec/case Outline Designa	ition:
To-236	
Mounting Method:	
Terminal	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
75.0 reverse breakdown voltage, instantaneous	
Current Rating Per Characteristic:	
200.00 milliamperes collector current, dc absolute	
Power Rating Per Characteristic:	
300.0 milliwatts small-signal input power, common-collector absolute	
Maximum Operating Tempurature Per Measurement Point:	
150.0 degrees celsius junction	
Terminal Type And Quantity:	
3 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	